## NSN 5961-01-390-7168

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-390-7168 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.165 inches and 0.195 inches **Overall Height:** Between 0.070 inches and 0.085 inches Overall Width: Between 0.070 inches and 0.085 inches **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, instantaneous and 50.0 working peak reverse voltage **Current Rating Per Characteristic:** 300.00 milliamperes forward current, average absolute and 2.50 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 case **Specification Data:** 81349-mil-s-19500/578 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No